

30V P-Channel Enhancement Mode MOSFET

Voltage -30 V

Current

-42 A

Features

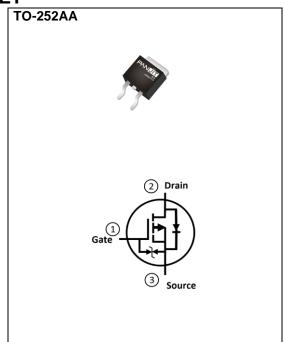
- RDS(ON), VGS@-10V, ID@-20A<15m Ω
- RDS(ON), VGS@-4.5V, ID@-10A<26m Ω
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.3217 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-30	V	
Gate-Source Voltage		V_{GS}	±25	V	
Continuous Drain Current(Note 3)	T _C =25°C	l _D	-42		
	T _C =100°C		-30	Α	
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	-128		
Power Dissipation	T _C =25°C	Po	43	107	
	T _C =100°C		21	W	
Continuous Drain Current(Note 4)	T _A =25°C	l _D	-11.2	^	
	T _A =70°C		-9.4	А	
Power Dissipation	T _A =25°C	5	3	W	
	T _A =70°C	PD	2.1		
Single Pulse Avalanche Energy ^(Note 5)		Eas	56	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	R _{0JC}	3.5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	50		



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA -		-	-	.,	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.8	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A	-	12	15	mΩ	
		V _{GS} =-4.5V, I _D =-10A	-	20	26		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current		V _{GS} =±25V, V _{DS} =0V	-	-	±10	uA	
	IGSS	V _{GS} =±10V, V _{DS} =0V	-	-	±1		
Dynamic ^(Note 6)							
Total Gate Charge	Qg	N 04N/ L 00A	-	32	-	nC	
Gate-Source Charge	Qgs	V _{DS} =-24V, I _D =-20A,	-	5	-		
Gate-Drain Charge	Q_{gd}	V _{GS} =-10V	-	10	-		
Input Capacitance	Ciss		-	1270	-		
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V,	-	190	-	pF	
Reverse Transfer Capacitance	Crss	f=1MHz	-	170	-		
Gate resistance	Rg	f=1MHz	-	7	-	Ω	
Turn-On Delay Time	td _(on)		-	7	-		
Turn-On Rise Time	tr	V _{DS} =-24V, I _D =-20A,	-	9	-	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=-10V$, $R_{G}=3\Omega$	-	32	-		
Turn-Off Fall Time	tf	(11010-2)	-	39	-		
Drain-Source Diode			•				
Diode Forward Current	Is	T 05°0	-	-	-42		
Pulsed Diode Forward Current	I _{SM}	T _C =25°C	_	-	-128	A	
Diode Forward Voltage	V _{SD}	Is=-20A, V _{GS} =0V	-	-0.9	-1.3	V	
Reverse Recovery Time	Trr	V _{GS} =0V, I _S =-20A	-	18	-	ns	
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	8	-	nC	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS} =-15A, V_{DD} =-30V, V_{GS} =-10V, Starting T_{J} =25°C.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

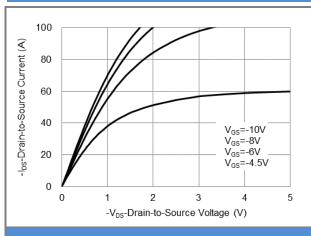


Fig.1 On-Region Characteristics

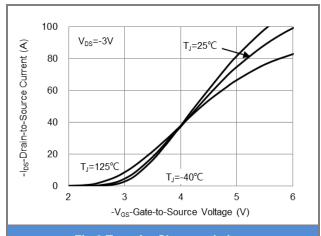


Fig.2 Transfer Characteristics

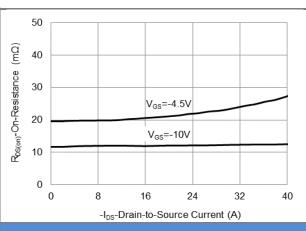


Fig.3 On-Resistance vs. Drain Current

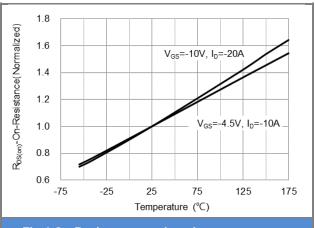
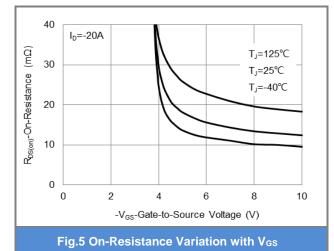
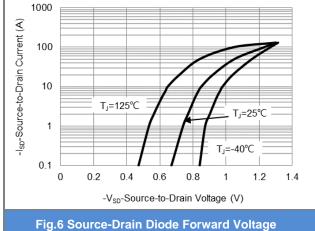


Fig.4 On-Resistance vs. Junction temperature







TYPICAL CHARACTERISTIC CURVES

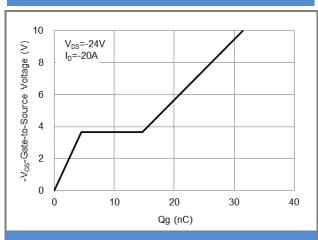


Fig.7 Gate-Charge Characteristics

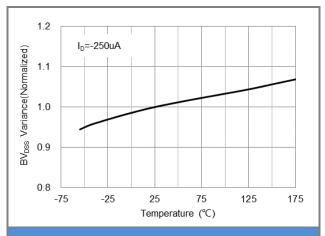


Fig.8 Breakdown Voltage Variation vs. Temperature

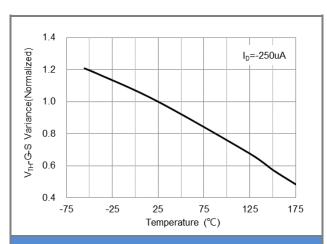


Fig.9 Threshold Voltage Variation with Temperature

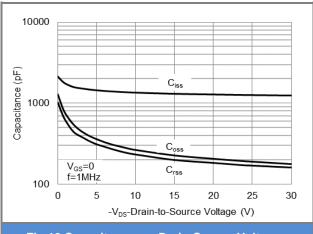


Fig.10 Capacitance vs. Drain-Source Voltage

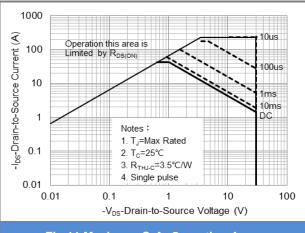


Fig.11 Maximum Safe Operating Area

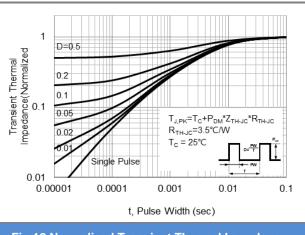


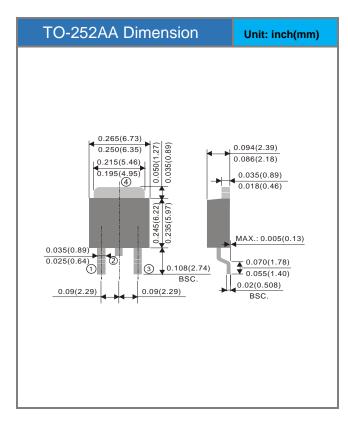
Fig.12 Normalized Transient Thermal Impedance

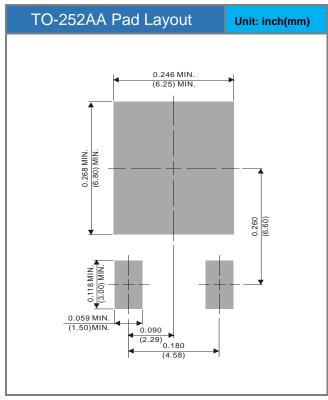


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJD45P03E-AU	TO-252AA	3K pcs / 13" reel	D45P03E

Packaging Information & Mounting Pad Layout







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